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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/551,266	09/29/2005	Toshiro Akino	9694D-000025/US	3385
30593 7590 06/25/2007 HARNESSE, DICKEY & PIERCE, P.L.C. P.O. BOX 8910 RESTON, VA 20195			EXAMINER O TOOLE, COLLEEN J	
			ART UNIT 2816	PAPER NUMBER
			MAIL DATE 06/25/2007	DELIVERY MODE PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Office Action Summary	Application No.		Applicant(s)	
	10/551,266		AKINO, TOSHIRO	
	Examiner		Art Unit	
	Colleen O'Toole		2816	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 29 September 2005.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-8 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1-8 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☒ All b) ☐ Some * c) ☐ None of:
1. ☒ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. _____.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413) |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | Paper No(s)/Mail Date. _____ |
| 3) <input checked="" type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08) | 5) <input type="checkbox"/> Notice of Informal Patent Application |
| Paper No(s)/Mail Date <u>9/29/05, 10/31/05</u> . | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Drawings

1. Figures 10-13 should be designated by a legend such as --Prior Art-- because only that which is old is illustrated. See MPEP § 608.02(g). Corrected drawings in compliance with 37 CFR 1.121(d) are required in reply to the Office action to avoid abandonment of the application. The replacement sheet(s) should be labeled "Replacement Sheet" in the page header (as per 37 CFR 1.84(c)) so as not to obstruct any portion of the drawing figures. If the changes are not accepted by the examiner, the applicant will be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

2. Claims 1 and 2 are rejected under 35 U.S.C. 102(b) as being anticipated by Jin et al. ("On the Power Dissipation in Dynamic Threshold Silicon-on-Insulator CMOS Inverter," IEEE, hereafter Jin).

Claim 1: Jin teaches a lateral bipolar CMOS integrated circuit comprising:

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an inverter circuit (Figure 3) comprising an n-channel MOS transistor (transistor in stage n-1 connected to GND) and a p-channel MOS transistor (transistor in stage n-1 connected to Vdd), and having four terminals of:

a gate input terminal Vin ("1" connected to stage n-1) connected with the gates of the n-channel MOS transistor and the p-channel MOS transistor;

an output terminal Vout ("0" connected between stages n-1 and n) connected with the drains of the n-channel MOS transistor and the p-channel MOS transistor;

a p-type base terminal connected with a p-type substrate of the n-channel MOS transistor (node between two diodes connected to the source and drain of the transistor in stage n-1 connected to Vdd); and

an n-type base terminal connected with an n-type substrate of the p-channel MOS transistor (node between two diodes connected to the source and drain of the transistor in stage n-1 connected to GND),

wherein the n-channel MOS transistor operates in a hybrid mode which is the hybrid of an operation mode of the MOS transistor and an operation mode of an npn lateral bipolar transistor which is inherent in the n-channel MOS transistor, and

the p-channel MOS transistor operates in a hybrid mode which is the hybrid of an operation mode of the MOS transistor and an operation mode of a pnp lateral bipolar transistor which is inherent in the p-channel MOS transistor. The inverter chain in Figure 3 teaches the structure of n-channel and p-channel MOS transistors and will inherently function in a hybrid mode.

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Claim 2: Jin further teaches that the gate input terminal V_{in} ("1" connected to stage n-1), the p-type base terminal and the n-type base terminal are input terminals of the inverter circuit (Figure 3), and the output terminal V_{out} ("0" connected between stages n-1 and n) is an output terminal of the inverter circuit (Figure 3), and

the inverter circuit outputs, at the output terminal V_{out} ("0" connected between stages n-1 and n), a high-level or low-level voltage fed to the gate input terminal V_{in} as an inverted level voltage (Figure 3).

Claim Rejections - 35 USC § 103

3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

4. Claims 3-8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Jin in view of Yamaguchi et al. (U.S. Patent 5,557,231, hereafter Yamaguchi).

Claim 3: Jin teaches the limitations of claims 1 and 2 above. Jin does not teach the limitations of claim 3. Yamaguchi teaches a current source I_{bp} (321) in Figure 13 connected with the p-type base terminal of the n-channel MOS and a current source I_{bn} (323) connected with the n-type base terminal of the p-channel MOS transistor,

wherein currents from the current source I_{bp} and the current source I_{bn} are maintained at 0 when the input voltage to the gate input terminal V_{in} is approximately

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constant at a high level or low level (according to control signal CNT), when the input voltage to the gate input terminal V_{in} switches from the low level to the high level, a forward pulse current flows from the current source I_{bp} to the p-type base terminal in synchronization to switching, and

when the input voltage to the gate input terminal V_{in} switches from the high level to the low level, a forward pulse current flows from the current source I_{bn} to the n-type base terminal in synchronization to switching (Figure 13, column 12 lines 50-59). It would have been obvious to one skilled in the art at the time the invention was made to have used the controlled transistors taught by Yamaguchi in the inverter taught by Jin to reduce current consumption and increase the speed of operation in the inverter circuit (column 4 lines 11-16).

Claim 4: Jin further teaches a voltage source V_{dd} (V_{dd} , Figure 3) and a ground source G_{nd} (GND , Figure 3). Jin does not teach two current sources I_{bp} and I_{bn} . Yamaguchi teaches a current source I_{bp} (321) is formed by a pull-up n-channel MOS transistor comprising a source terminal, a drain terminal and a substrate terminal, the drain terminal is connected with the p-type base terminal (base terminal of the NMOS transistor connected to ground taught by Jin), and the source terminal and the substrate terminal are connected with the voltage source V_{dd} (V_{BB1}), and the current source I_{bn} is formed by a pull-down n-channel MOS transistor (323) comprising a source terminal, a drain terminal and a substrate terminal, the drain terminal is connected with the n-type base terminal (base terminal of the PMOS transistor connected to V_{dd} taught by Jin),

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and the source terminal and the substrate terminal are connected with the ground source Gnd (VBB3) (Figure 13). It would have been obvious to one skilled in the art at the time the invention was made to have used a PMOS current source instead of an NMOS current source to fit design parameters. The selection of something based on its known suitability for its intended use has been held to support a *prima facie* case of obviousness. *Sinclair & Carroll Co. v. Interchemical Corp.*, 325 U.S. 327, 65 USPQ 297 (1945).

Claims 5-8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Jin in view of Yamaguchi, and further in view of Shimomura et al. (as cited in the Information Disclosure Statement dated September 29th, 2005). Claims 5 through 8 recite the same limitation and only differ in their parent claims.

Claims 5-8: Jin and Yamaguchi teach the circuits of claims 1, 2, 3, and 4. Neither Jin nor Yamaguchi teach that the inverter circuit is used as a CMOS standard cell and in hybrid mode. Shimomura teaches that the inverter circuit comprising the n-channel MOS transistor and the p-channel MOS transistor is used as a CMOS standard cell in the operation mode of the MOS transistor, but is used in the hybrid mode when a large load is connected with an output from the CMOS standard cell ([0016]). It would have been obvious to one of ordinary skill in the art at the time the invention was made to have used the functionality of the semiconductor integrated circuit taught by Shimomura in the circuit taught by Jin and Yamaguchi to reduce power consumption ([0016]).

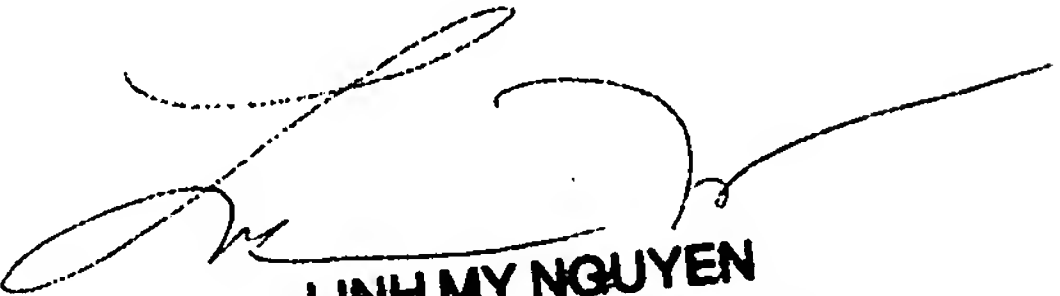
Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Colleen O'Toole whose telephone number is (571) 270-1273. The examiner can normally be reached on M-F 8:30-5:00pm EST.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert J. Pascal can be reached on (571) 272-1769. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.


CJO


LINH MY NGUYEN
PRIMARY EXAMINER